- Adjustable Gain to 400 Typ
- No Frequency Compensation Required
- Low Noise . . . 3 μV Typ V_n

description

This device is a monolithic two-stage video amplifier with differential inputs and differential outputs. It features internal series-shunt feedback that provides wide bandwidth, low phase distortion, and excellent gain stability. Emitterfollower outputs enable the device to drive capacitive loads. All stages are current-source biased to obtain high common-mode and supply-voltage rejection ratios.

The differential gain is typically 400 when the gain adjust pins are connected together, or amplification may be adjusted for near 0 to 400 by the use of a single external resistor connected between the gain adjustment pins A and B. No external frequency-compensating components are required for any gain option.

The device is particularly useful in magnetic-tape or disk-file systems using phase or NRZ encoding and in high-speed thin-film or plated-wire memories. Other applications include general-purpose video and pulse amplifiers.

The device achieves low equivalent noise voltage through special processing and a new circuit layout incorporating input transistors with low base resistance.

The TL592B is characterized for operation from 0°C to 70°C.

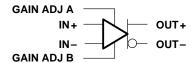
D8[†] OR P PACKAGE (TOP VIEW) 8 **∏** IN− IN+ 7 | GAIN ADJ B GAIN ADJ A V_{CC}-3 6 VCC+ OUT+ 5 OUT-D14[†] OR N PACKAGE (TOP VIEW) IN+[14 🛮 IN-13 NC NC 2 NC[] 3 12 NC GAIN ADJ A 1 4 11 GAIN ADJ B 10 V_{CC+} V_{CC} NC [] 6 9∏NC

†D8 and D14 are the codes to differentiate the 8-pin and 14-pin versions, respectively.

8**Π** OUT−

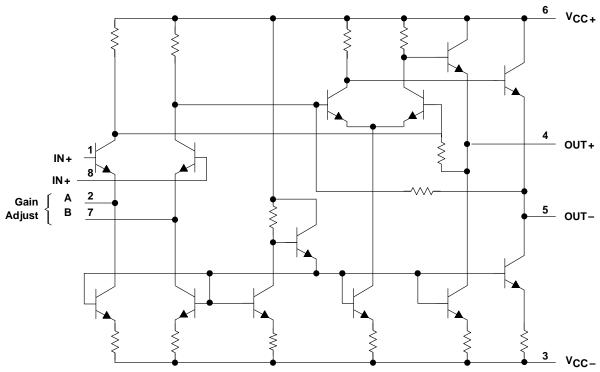
OUT+I

symbol





schematic



Pin numbers are for D8 and P packages.

absolute maximum ratings over operating free-air temperature (unless otherwise noted)

Supply voltage, V _{CC+} (see Note 1)	8 V
Supply voltage, V _{CC}	8 V
Differential input voltage	±5 V
Voltage range, any input	V _{CC+} to V _{CC-}
Output current	10 mA
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range	0°C to 70°C
Storage temperature range	65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

NOTES: 1. All voltage values except differential input voltages are with respect to the midpoint between V_{CC+} and V_{CC-} .

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR	DERATE ABOVE T _A	T _A = 70°C POWER RATING	
D8	530 mW	5.8 mW/°C	59°C	464 mW	
D14	530 mW	N/A	N/A	530 mW	
N	530 mW	N/A	N/A	530 mW	
Р	530 mW	N/A	N/A	530 mW	



recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC+}	3	6	8	V
Supply voltage, V _{CC} _	-3	-6	-8	V
Operating free-air temperature, T _A	0		70	°C

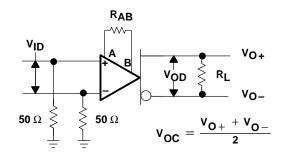
electrical characteristics at specified free-air temperature, V_{CC \pm} = \pm 6 V, R_L = 2 k Ω (unless otherwise noted)

PARAMETER		TEST FIGURE TEST CONDITIONS†		TA	MIN	TYP	MAX	UNIT	
Λ	Large-signal differential	1	V _{OPP} = 3 V,	$R_L = 2 k\Omega$,	25°C	300	400	500	V/V
AVD	voltage amplification		$R_{AB} = 0$		0°C to 70°C	250		600	
A _{VD2}	Large-signal differential voltage amplification	1	$V_{OPP} = 3 V$, $R_{AB} = 1 k\Omega$	$R_L = 2 k\Omega$,	25°C		13		V/V
BW	Bandwidth (-3 dB)	2	V _{OPP} = 1 V,	$R_{AB} = 0$	25°C		50		MHz
IIO	Input offset current				25°C		0.4	5	μΑ
					0°C to 70°C			6	
IB	lanut biog gymant				25°C		9	30	μА
	Input bias current				0°C to 70°C			40	μΑ
.,	Common-mode input	3			25°C	±1			V
VICR	voltage range	3			0°C to 70°C	±1			
Voc	Common-mode output voltage	1	R _L = ∞		25°C	2.4	2.9	3.4	٧
\/	Outrot effect velters	4	V _{ID} = 0,	R _{AB} = ∞,	25°C		0.35	0.75	V
V00	Output offset voltage	1	R _L = ∞		0°C to 70°C			1.5	
M	Peak-to-peak output voltage swing	1	$R_L = 2 k\Omega$,	D 0	25°C	3	4		V
VOPP				$R_{AB} = 0$	0°C to 70°C	2.8			
	Input resistance		V _{OD} = 1 V,	R _{AB} = 0	25°C		4		l-O
rį					0°C to 70°C		3.6		kΩ
ro	Output resistance				0°C to 70°C			30	Ω
Ci	Input capacitance				25°C		5		pF
CMRR	Common-mode rejection ratio	3	$V_{IC} = \pm 1 V$, $R_{AB} = 0$	f = 100 kHz	25°C –	60	86		dB
				f = 5 MHz			60		
CIVINN				f = 100 kHz	0°C to 70°C 50	50			
				f = 5 MHz			60		
ksvr	Supply voltage rejection ratio ($\Delta V_{CC}/\Delta V_{IO}$)	4	ΔV_{CC} + = $\pm 0.5 \text{ V}$,		25°C	50	70		dВ
			$\Delta V_{CC} - = \pm 0.5 \text{ V},$		0°C to 70°C	50			
V _n	Broadband equivalent input noise voltage	4	BW = 1 kHz to 10 MHz		25°C		3		μV
t _{pd}	Propagation delay time	2	$\Delta V_O = 1 V$		25°C		7.5		ns
t _r	Rise time	2	$\Delta V_O = 1 V$		25°C		10.5		ns
I _{sink(max)}	Maximum output sink current		V _{ID} = 1 V,	۷, و= 0		3	4		mA
Icc	Supply current		No load,	No signal	25°C		18	24	mΛ
					0°C to 70°C	1		27	mA

[†] RAB is the gain-adjustment resistor connected between gain-adjust pins A and B. If not specified for a particular parameter, its value is irrelevant to that parameter.



PARAMETER MEASUREMENT INFORMATION



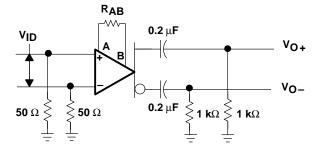
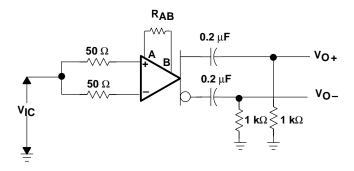


Figure 1

Figure 2



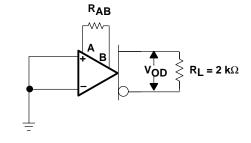


Figure 3

Figure 4

TYPICAL CHARACTERISTICS

LARGE-SIGNAL DIFFERENTIAL **VOLTAGE AMPLIFICATION SUPPLY VOLTAGE** 500 $R_{AB} = 0$ f = 1 kHz T_A = 25°C 400 See Figure 1 Voltage Amplification – V/V 300 200 100 0 $\pm \textbf{5}$ $\pm \textbf{6}$ ± 3 ± 4 ± 7 ±8 V_{CC±} - Supply Voltage - V

LARGE-SIGNAL DIFFERENTIAL
VOLTAGE AMPLIFICATION
VS

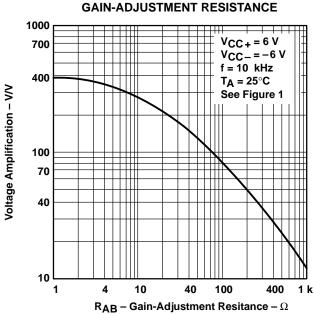


Figure 5 Figure 6

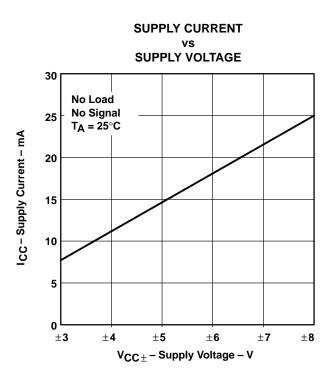


Figure 7

IMPORTANT NOTICE

Texas Instruments (TI) reserves the right to make changes to its products or to discontinue any semiconductor product or service without notice, and advises its customers to obtain the latest version of relevant information to verify, before placing orders, that the information being relied on is current.

TI warrants performance of its semiconductor products and related software to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

Certain applications using semiconductor products may involve potential risks of death, personal injury, or severe property or environmental damage ("Critical Applications").

TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, INTENDED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT APPLICATIONS, DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS.

Inclusion of TI products in such applications is understood to be fully at the risk of the customer. Use of TI products in such applications requires the written approval of an appropriate TI officer. Questions concerning potential risk applications should be directed to TI through a local SC sales office.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards should be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance, customer product design, software performance, or infringement of patents or services described herein. Nor does TI warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used.

Copyright © 1996, Texas Instruments Incorporated